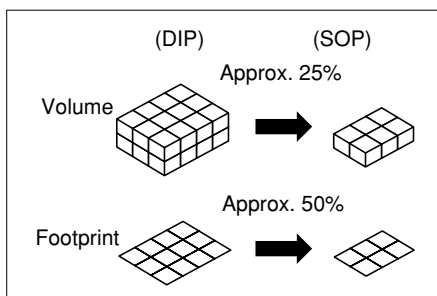
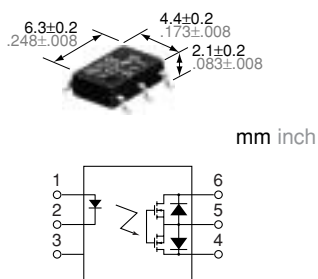


NAIS

**Lower output capacitance and on resistance.
High speed switching.
(Turn on time: 0.1ms,
Turn off time: 0.05ms).**

RF PhotoMOS (AQV220NS)



PhotoMOS relay has only 30 pA even with the rated load voltage of 80 V (AQV225NS).

4. Controls low-level analog signals
PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. Tape and reel
The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

FEATURES

1. 1-channel (Form A) in super miniature design

The device comes in a super-miniature SO package measuring (W) 4.4 × (L) 6.3 × (H) 2.1 mm (W).173 × (L).248 × (H).083 inch —approx. 25% of the volume and 50% of the footprint size of DIP type PhotoMOS Relays.

2. Low capacitance between output terminals ensure high response speed:

The capacitance between output terminals is small, typically 10 pF. This enables for a fast operation speed of 200 μs.

3. Low-level off state leakage current:

The SSR has an off state leakage current of several milliamperes, whereas the

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines

TYPES

1. AC/DC type

Output rating*		Part No.		Packing quantity in tape and reel
		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	
Load voltage	Load current	1 Form A	1 Form A	1,000 pcs.
80 V	120 mA	AQV225NSX	AQV225NSZ	
200 V	50 mA	AQV227NSX	AQV227NSZ	
400 V	40 mA	AQV224NSX	AQV224NSZ	

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 75 pcs.; Case: 1,500 pcs.)

(2) For space reasons, the top two letters of the product number "AQ" are omitted on the product seal. The package type indicator "X" and "Z" are also omitted from the seal. (Ex. the label for product number AQV224NS is V224NS).

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV225NS	AQV227NS	AQV224NS	Remarks	
Input	LED forward current	I_F		50 mA			f = 100 Hz, Duty factor = 0.1%	
	LED reverse voltage	V_R		5 V				
	Peak forward current	I_{FP}		1 A				
	Power dissipation	P_{in}		75 mW				
Output	Load voltage (peak AC)	V_L		80 V	200 V	400 V	A connection: Peak AC, DC B, C connection: DC	
	Continuous load current	I_L		A	0.12 A	0.05 A		0.04 A
				B	0.15 A	0.06 A		0.05 A
				C	0.25 A	0.08 A		0.06 A
	Peak load current	I_{peak}			0.36 A	0.15 A		0.12 A
Power dissipation	P_{out}		450 mW					
Total power dissipation		P_T		500 mW				
I/O isolation voltage		V_{iso}		1,500 V AC				
Temperature limits	Operating	T_{opr}		-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures	
	Storage	T_{stg}		-40°C to +100°C -40°F to +212°F				

RF PhotoMOS (AQV22○NS)

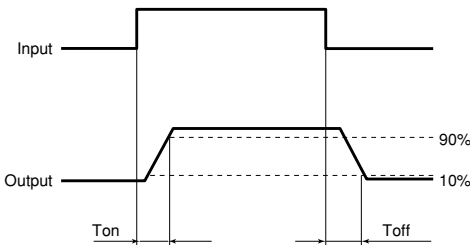
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV225NS	AQV227NS	AQV224NS	Remarks	
Input	LED operate current	Typical	I _{Fon}	0.7 mA			I _L = Max.	
		Maximum		3 mA				
	LED turn off current	Minimum	I _{Foff}	0.4 mA			I _L = Max.	
		Typical		0.65 mA				
LED dropout voltage	Typical	V _F	1.25 V (1.14 V at I _F = 5 mA)			I _F = 50 mA		
	Maximum		1.5 V					
Output	On resistance	Typical	R _{on}	A	7.0 Ω	30 Ω	70 Ω	I _F = 5 mA I _L = Max. Within 1 s on time
		Maximum			10.0 Ω	50 Ω	100 Ω	
		Typical	R _{on}	B	3.5 Ω	16 Ω	55 Ω	
		Maximum			5.0 Ω	25 Ω	70 Ω	
	Typical	R _{on}	C	1.8 Ω	8 Ω	28 Ω	I _F = 5 mA I _L = Max. Within 1 s on time	
	Maximum			2.5 Ω	12.5 Ω	35 Ω		
	Output capacitance	Typical	C _{out}	10 pF			I _F = 0 V _B = 0 f = 1 MHz	
		Maximum		15 pF				
Off state leakage current	Typical	I _{leak}	30 pA		90 pA	I _F = 0 V _L = Max.		
	Maximum		10 nA					
Transfer characteristics	Turn on time*	Typical	T _{on}	0.25 ms	0.12 ms	0.1 ms	I _F = 5 mA I _L = Max.	
		Maximum		0.5 ms				
	Turn off time*	Typical	T _{off}	0.05 ms			I _F = 5 mA I _L = Max.	
		Maximum		0.2 ms				
	I/O capacitance	Typical	C _{iso}	0.8 pF			f = 1 MHz V _B = 0	
		Maximum		1.5 pF				
Initial I/O isolation resistance	Minimum	R _{iso}	1,000 MΩ			500 V DC		

Note: Recommendable LED forward current I_F = 5 mA.

For type of connection

*Turn on/Turn off time



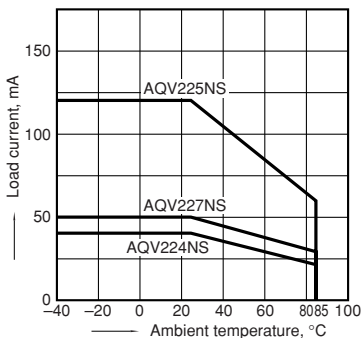
- For Dimensions
- For Schematic and Wiring Diagrams
- For Cautions for Use

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

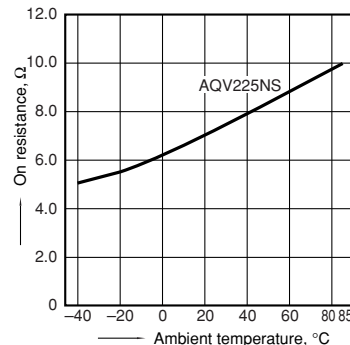
Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

Type of connection: A



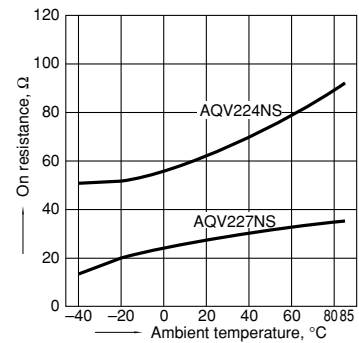
2.-(1) On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



2.-(2) On resistance vs. ambient temperature characteristics

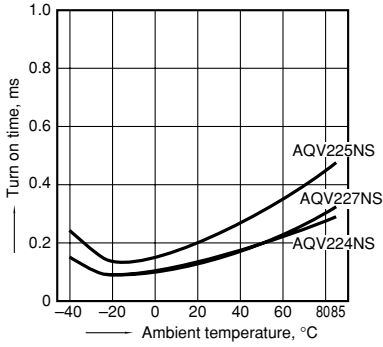
Measured portion: between terminals 4 and 6;
LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



RF PhotoMOS (AQV22○NS)

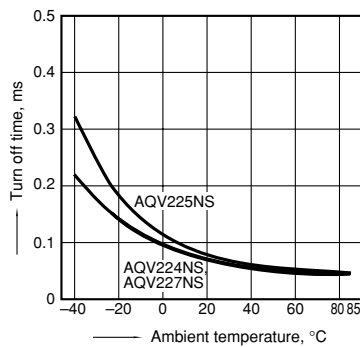
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



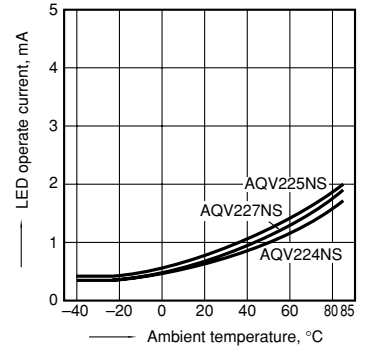
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



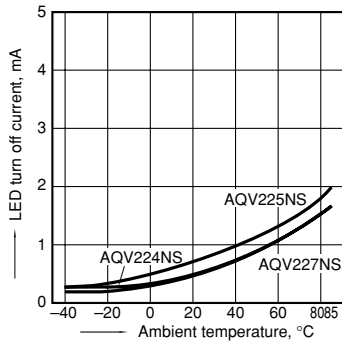
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



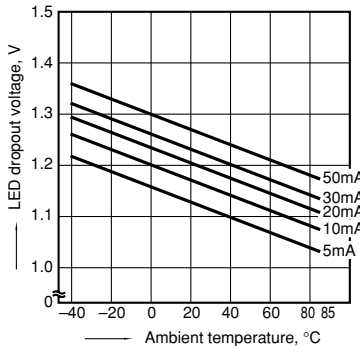
6. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



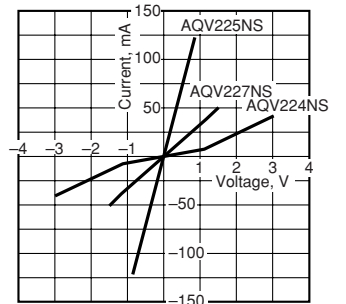
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types;
LED current: 5 to 50 mA



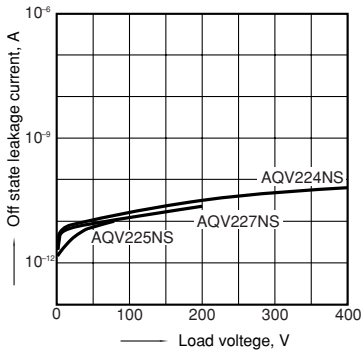
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



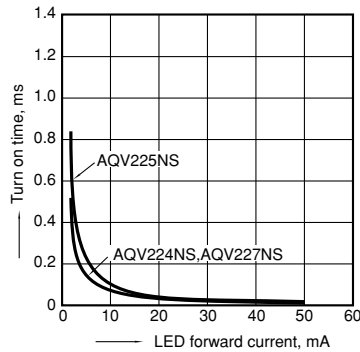
9. Off state leakage current

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



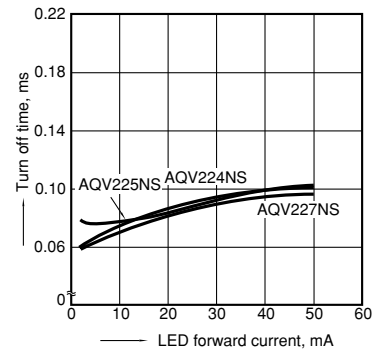
10. LED forward current vs. turn on time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



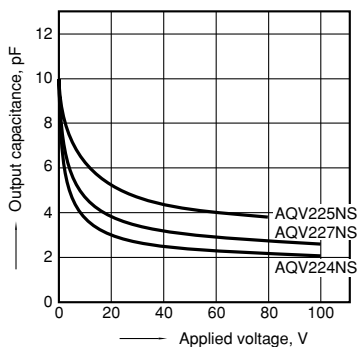
11. LED forward current vs. turn off time characteristics

Measured portion: between terminals 4 and 6;
Load voltage: Max. (DC);
Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



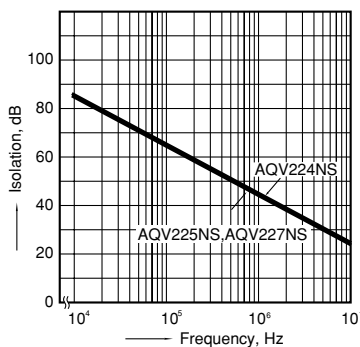
12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz, 30 mVrms;
Ambient temperature: 25°C 77°F



13. Isolation characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



14. Insertion loss characteristics (50 Ω impedance)

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F

